



A Product Line of Diodes Incorporated



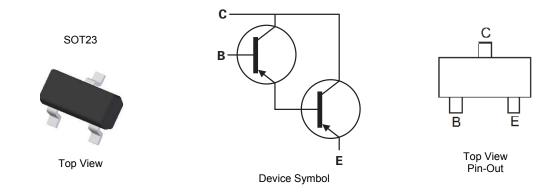
60V PNP DARLINGTON TRANSISTOR IN SOT23

Features

- BV_{CEO} > -60V
- Darlington Transistor h_{FE} > 10k @ 100mA for high gain
- I_C = -500mA High Continuous Collector Current
- Complementary Darlington PNP Type: BCV47
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight 0.008 grams (approximate)



Ordering Information (Notes 4 & 5)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCV46TA	AEC-Q101	ZFE	7	8	3,000
BCV46QTA	Automotive	ZFE	7	8	3,000

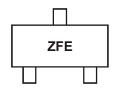
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen and Antimony free, "Green" and Lead-Free.
Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and

<1000ppm antimony compounds. 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified.

5. For packaging details, go to our website at http://www.diodes.com

Marking Information



ZFE = Product Type Marking Code





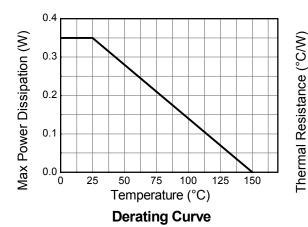
Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

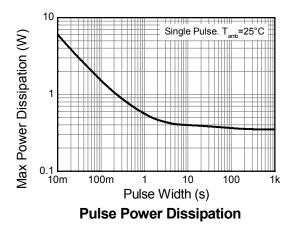
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-80	V
Collector-Emitter Voltage	V _{CEO}	-60	V
Emitter-Base Voltage	V _{EBO}	-10	V
Continuous Collector Current	Ic	-500	mA
Peak Pulse Current	I _{CM}	-800	mA
Base Current	IB	-100	mA

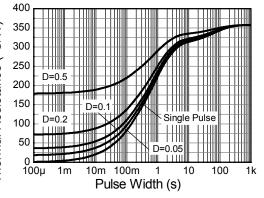
Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Rower Dissinction	(Note 6)	Р	310	mW	
Power Dissipation	(Note 7)	PD	350		
Thermal Desistance Junction to Ambient	(Note 6)	P	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 7)	$R_{ extsf{ heta}JA}$	357		
Thermal Resistance, Junction to Leads (Note 8)		R _{θJL}	350	°C/W	
Operating and Storage Temperature Range		T _J ,T _{STG}	-55 to +150	°C	

6. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; the device is Notes: measured when operating in a steady-state condition. 7. Same as note (6), except the device is mounted on 15mm x 15mm FR4 PCB. 8. Thermal resistance from junction to solder-point (at the end of the leads).







Transient Thermal Impedance





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						·
Collector-Base Breakdown Voltage	BV _{CBO}	-80	-	-	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-60	-	-	V	I _C = -10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-10	-	-	V	I _E = -10μΑ
Collector Cutoff Current	І _{сво}	-	<1	-100	nA	V _{CB} = -60V
		-	-	-10	μA	V _{CB} = -60V, T _A = +150°C
Emitter Cutoff Current	I _{EBO}	-	<1	-100	nA	$V_{EB} = -4V$
ON CHARACTERISTICS (Note 9)						
	h _{FE}	2,000	-	-		I_{C} = -100µA, V_{CE} = -1V
Static Forward Current Transfer Ratio		4,000	-	-	_	I_{C} = -10mA, V_{CE} = -5V
		10,000	-	-		I _C = -100mA, V _{CE} = -5V
		2,000	-	-		I _C = -500mA, V _{CE} = -5V
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	-	-1.0	V	I _C = - 100mA, I _B = -0.1mA
Base-Emitter Saturation Voltage	V _{BE(sat)}	-	-	-1.5	V	I _C = -100mA, I _B = -0.1mA
SMALL SIGNAL CHARACTERISTICS						
Transition Frequency	f _T	-	200	-	MHz	V _{CE} = -5V, I _C = -50mA, f = 20MHz
Output Capacitance	Cobo	-	4.5	-	pF	V _{CB} = -10V, f = 1MHz

Notes: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Тур

0.40

1.30

2.40

0.915

0.535

1.83

2.90

0.05

1.00

0.400

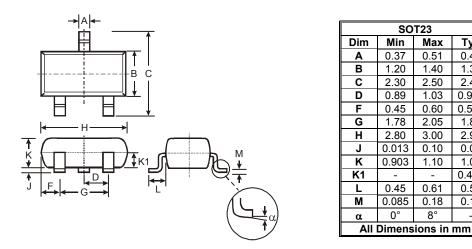
0.55

0.11



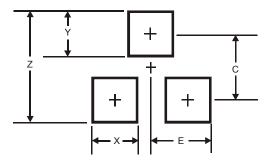
Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)			
Z	2.9			
Х	0.8			
Y	0.9			
С	2.0			
Е	1.35			





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